

L Number	Hits	Search Text	DB	Time stamp
1	76	dop\$4 same buffer same gallium same nitride same (silicon or arsenic)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/02 10:40
2	7	dop\$4 same gallium same nitride same (silicon or arsenic) near2 buffer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/02 10:42
5	86	gaasN	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/02 10:43
-	156	grad\$4 same (gallium adj nitride or gan)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/26 15:00
-	15	grad\$4 near2 (gallium adj nitride or gan)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/26 17:01
-	3	compress\$4 near2 stress\$4 same grad\$4 and 117/\$4.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/26 17:18
-	75	compress\$4 near2 stress\$4 and 117/\$4.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/26 17:19
-	20	compress\$4 near2 stress\$4 and 117/\$4.ccls. and (Gan or gallium adj nitride or "iii-v")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/27 10:12
-	21	117/98,105,107,89,93.ccls. and (gan or gallium adj nitride or "iii-v") same (grade or graded)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/27 10:19
-	17	117/98,105,107,89,93.ccls. and (gan or gallium adj nitride or "iii-v") same (graded)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/27 10:19